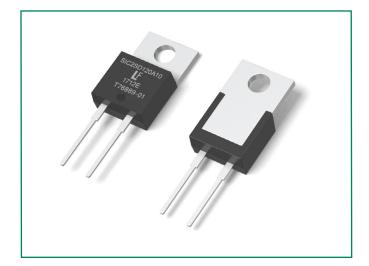


LSIC2SD120A10









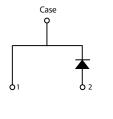
Description

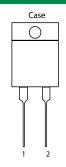
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- · Excellent surge capability
- · Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L





Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- · Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = Po PB--free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	1200	V	
DC Blocking Voltage	V _R	T _i = 25 °C	1200	V	
		T _c = 25 °C	28		
Continuous Forward Current	I _F	T _C = 125 °C	15	А	
		T _c = 151 °C	10		
Non-Repetitive Forward Surge Current	I _{FSM}	$T_{\rm C} = 25 {\rm ^{\circ}C}$, $T_{\rm P} = 10 {\rm ms}$, Half sine pulse	80	А	
Power Dissipation	D	T _C = 25 °C	136	W	
rower dissipation	P _{Tot}	T _C = 110 °C	59		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD120A10, 1200 V, 10 A, TO-220-2L

Electrical Characteristics

Characteristics	Symbol	Conditions	Value			
			Min.	Тур.	Max.	Unit
Forward Voltage	\/	I _F = 10 A, T _J = 25 °C	-	1.5	1.8	V
	V _F	I _F = 10 A, T _J = 175 °C	-	2.2		
Reverse Current	I _R	$V_{_{\rm R}} = 1200 \text{V}, T_{_{\rm J}} = 25 ^{\circ}\text{C}$	-	<1	100	μА
		V _R = 1200 V , T _J = 175 °C	-	10		
Total Capacitance		V _R = 1 V, f = 1 MHz	-	582		pF
	С	$V_{R} = 400 \text{ V, f} = 1 \text{ MHz}$	-	53		
		V _R = 800 V, f = 1 MHz	-	40		
Total Capacitive Charge	O _C	$V_{R} = 800 \text{ V}, \ \ Q_{c} = \int_{0}^{V_{R}} c(v)dv$	-	57		nC

Footnote: T₁ = +25 °C unless otherwise specified

Thermal Characteristics

Characteristics Sy		Symbol Conditions	Value			
	Symbol		Min.	Тур.	Max.	Unit
Thermal Resistance	R _{euc}	-	-	1.1		°C/W

Figure 1: Typical Foward Characteristics

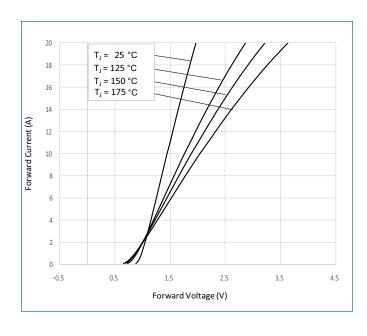


Figure 2: Typical Reverse Characteristics

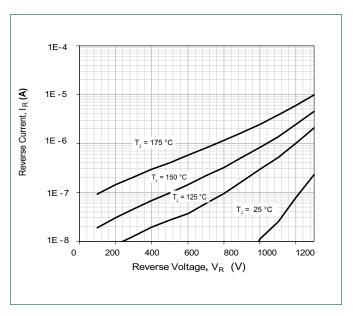




Figure 3: Power Derating

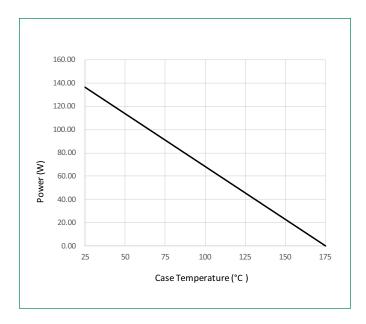


Figure 4: Current Derating

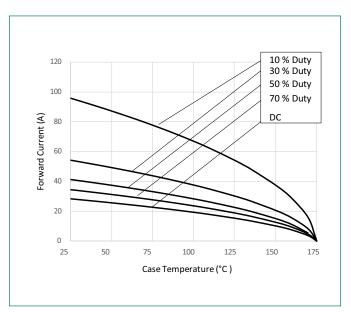


Figure 5: Capacitance vs. Reverse Voltage

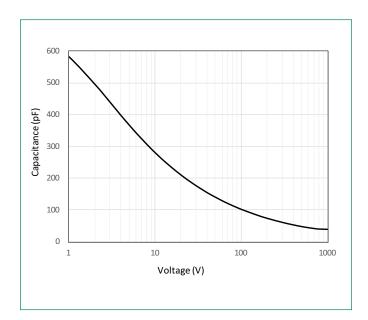
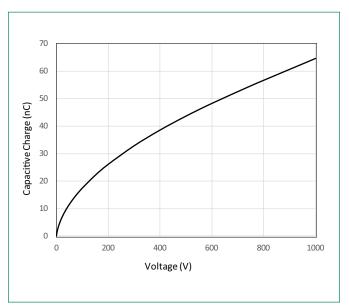


Figure 6: Capacitive Charge vs. Reverse Voltage



GEN2 SiC Schottky Diode LSIC2SD120A10, 1200 V, 10 A, TO-220-2L

Figure 7: Stored Energy vs. Reverse Voltage

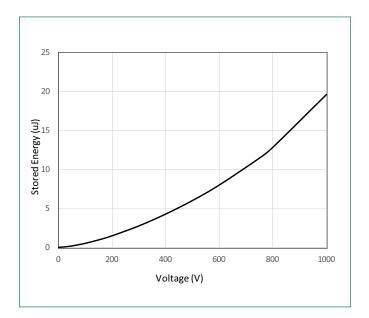
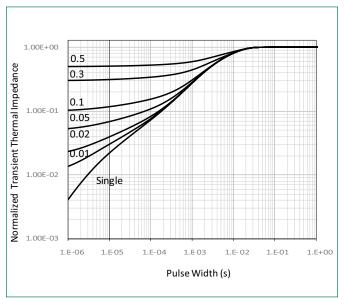
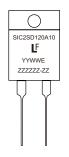


Figure 8: Transient Thermal Impedance



Part Numbering and Marking System



 SIC
 = SiC Diode

 2
 = Gen2

 SD
 = Schottky Diode

 120
 = Voltage Rating (1200 V)

 A
 = TO-220-2L

 10
 = Current Rating (10 A)

 YY
 = Year

 WW
 = Week

 E
 = Special Code

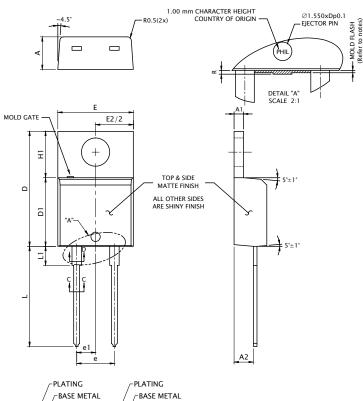
 ZZZZZZZ-ZZ
 = Lot Number

Packing Options

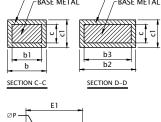
Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A10	SIC2SD120A10	Tube	1000



Dimensions-Package TO-220-2L

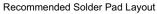


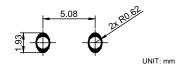
Symbol	Millimeters				
Symbol	Min	Nominal	Max		
Α	4.320	4.450	4.570		
A1	1.140	1.270	1.400		
A2	2.500	-	2.740		
b	0.690	-	0.880		
b1	0.680	-	0.870		
b2	1.230	-	1.390		
b3	1.220	1.270	1.380		
С	0.360	-	0.503		
c1	0.630	-	0.527		
D	14.900	-	15.600		
D1	8.615	-	9.017		
D2	12.840	-	12.950		
Е	10.000	10.180	10.360		
E1	7.570	7.610	7.680		
e1	2.490	2.540	2.590		
е	5.030	5.080	5.130		
H1	6.295	6.545	6.795		
L	13.000	13.500	14.00		
L1	2.390	-	3.250		
øΡ	3.710	3.840	3.960		
Q	2.650	-	3.050		
R	-	-	0.254		



D2

Ø



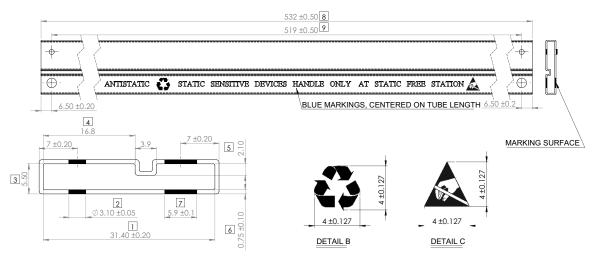




- NOTES:
 1. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 MM PER SIDE.
 THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREME OF PLASTIC BODY.
- 2. DIMENSIONS E2 & H1 DEFINE A ZONE WHERE STAMPING AND SINGULATION IRREGULARITIES RE ALLOWED.

GEN2 SiC Schottky Diode LSIC2SD120A10, 1200 V, 10 A, TO-220-2L

Packing Specification (Tube for TO-220-2L)



- NOTES:

 1. Material transparent extruded PVC with antistatic dipping

 2. Radius: 0.5 maximum unless otherwisen specified

 3. Critical areas: Labelled in Box

 4. All pin plugh poles are considered critical dimension

 5. Marking Font Type: Times new roman, 3.12 ±0.127 in height

 6. Material Thickness: 0.75 ±0.10

 7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°

 8. Unit: Millimeter (mm)

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